



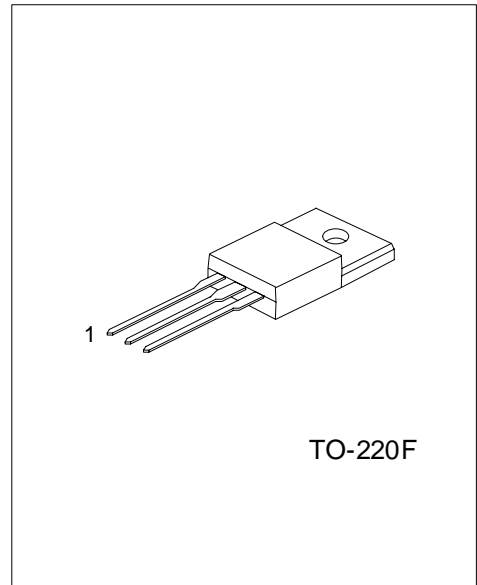
2SC4793

NPN SILICON TRANSISTOR

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FEATURES

- *High transition frequency
- *Power amplifier applications
- *Driver stage amplifier applications



*Pb-free plating product number:2SC4793L

ORDERING INFORMATION

Order Number		Package	Pin Assignment			Packing
Normal	Lead Free Plating		1	2	3	
2SC4793-x-TF3-T	2SC4793L-x-TF3-T	TO-220F	B	C	E	Tube

<p>2C4793L-x-TF3-T</p>	<p>(1) Packing Type</p> <p>(2) Package Type</p> <p>(3) Rank</p> <p>(4) Lead Plating</p>	<p>(1) T: Tube</p> <p>(2) TF3: TO-220F</p> <p>(3) refer to Classification of h_{FE}</p> <p>(4) L: Lead Free Plating, Blank: Pb/Sn</p>
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■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT	
Collector-Base Voltage	V_{CBO}	230	V	
Collector-Emitter Voltage	V_{CEO}	230	V	
Emitter-Base Voltage	V_{EBO}	5	V	
Collector Current	I_C	1	A	
Base Current	I_B	0.1	A	
Collector Power Dissipation	P_C	Ta=25	2.0	W
		Tc=25	20	W
Junction Temperature	T_J	+150		
Storage Temperature Range	T_{STG}	-55 ~ +150		

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.
Absolute maximum ratings are stress ratings only and functional device operation is not implied.

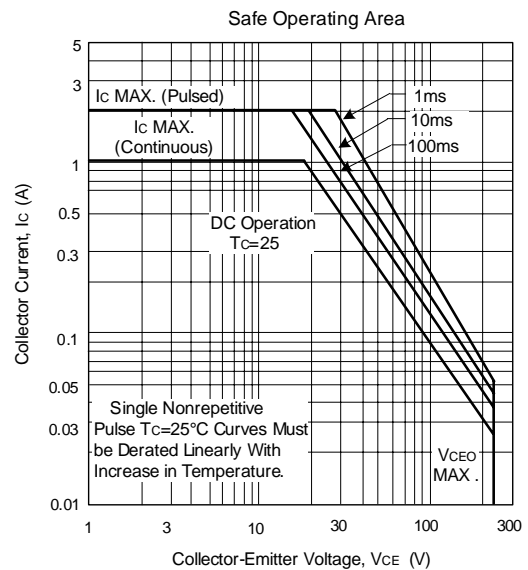
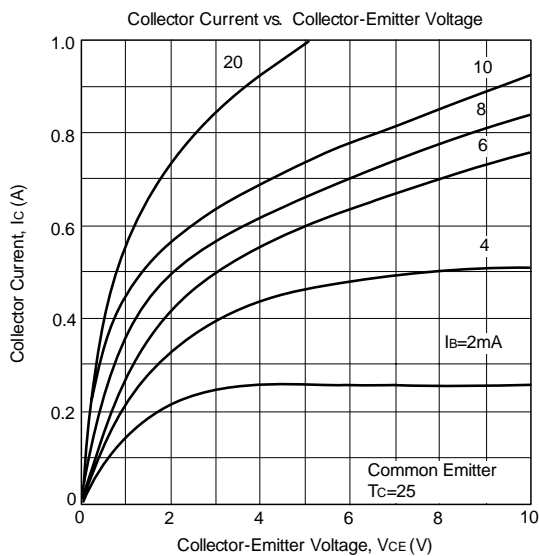
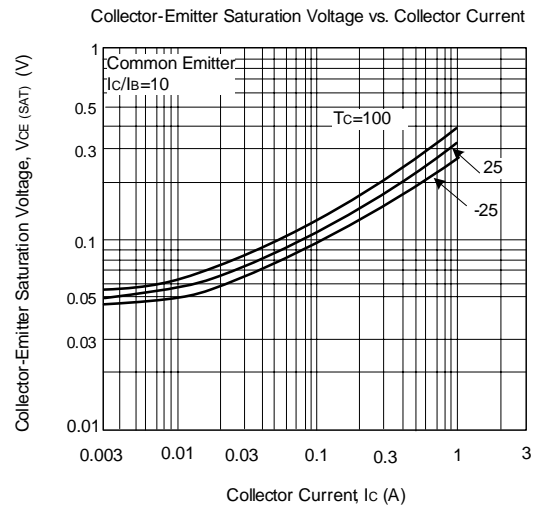
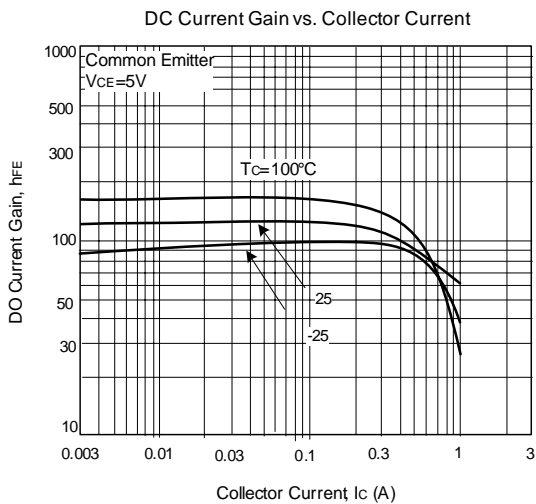
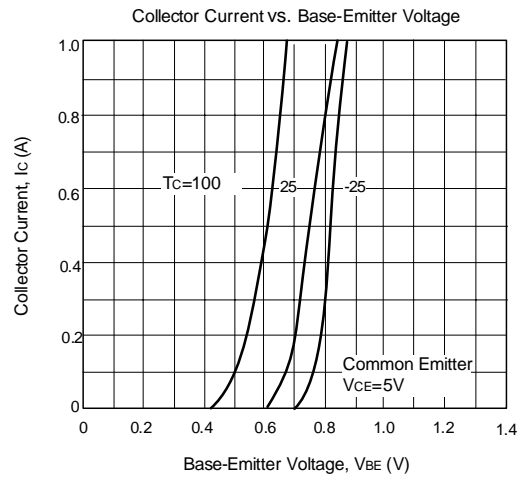
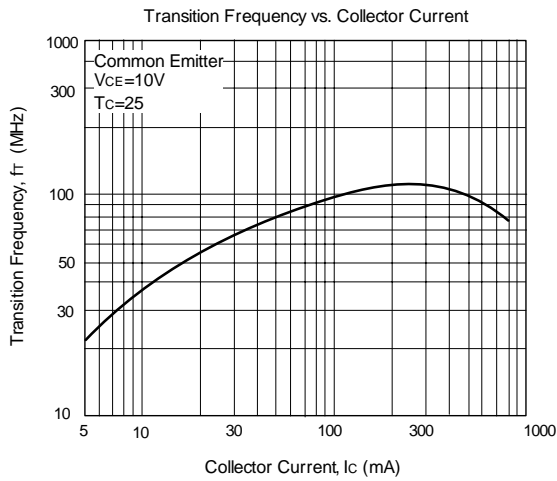
■ ELECTRICAL CHARACTERISTICS (Ta=25°C, unless others specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Breakdown Voltage	BV_{CEO}	$I_C=10mA, I_B=0$	230			V
Base -Emitter Voltage	V_{BE}	$V_{CE}=5V, I_C=500mA$			1.0	V
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C=500mA, I_B=50mA$			1.5	V
Collector Cut-off Current	I_{CBO}	$V_{CB}=230V, I_E=0$			1.0	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=5V, I_C=0$			1.0	μA
DC Current Gain	h_{FE}	$V_{CE}=5V, I_C=100mA$	100		320	
Transition Frequency	f_T	$V_{CE}=10V, I_C=100mA$		100		MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10V, I_E=0, f=1MHz$		20		pF

■ CLASSIFICATION OF h_{FE}

RANK	A	B
RANGE	100-200	180-320

TYPICAL CHARACTERISTICS



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